Initial Release



Features

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- Low input capacitance
- ☐ Fast switching speeds
- Low on resistance
- ☐ Free from secondary breakdown
- ☐ Low input and output leakages

Application

- Normally-on switches
- Solid state relays
- Battery operated systems
- Converters
- Linear amplifiers
- Constant current sources
- ☐ Telecom

Absolute Maximum Ratings

Drain-to-Source Voltage	BV_{DSX}
Drain-to-Gate Voltage	BV_{DGX}
Gate-to-Source Voltage	±20V
Operating and Storage Temperature	-55°C to +150°C
Soldering Temperature*	300°C

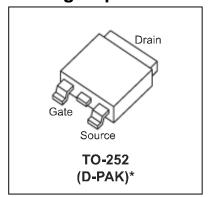
^{*} Distance of 1.6mm from case for 10 seconds.

General Description

This low threshold depletion-mode (normally-on) transistor utilizes an advanced vertical DMOS structure and Supertex's well-proven silicon-gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors and with the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally-induced secondary breakdown.

Supertex's vertical DMOS FET is ideally suited to a wide range of switching and amplifying applications where very low threshold voltage, high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

Package Option



^{** &}quot;Green" Certified Package

Ordering Information

Order Number / Package	BV _{DSX} / BV _{DGX}	D (max)	I _{DSS} (typ)	
TO-252	DV _{DSX} / DV _{DGX}	R _{DS(ON)} (max)		
DN2470K4	700V	42Ω	500mA	
DN2470K4-G **	700V	42Ω	500mA	



Thermal Characteristics

Package	I _{D(continuous)} *	I _{D(pulsed)}	Power Dissipation @ T _A =25°C	° C/W	θ _{JA} °C/W	I _{DR} *	I _{DRM}	
TO-252	170mA	500mA	2.5W**	6.25	50**	170mA	500mA	

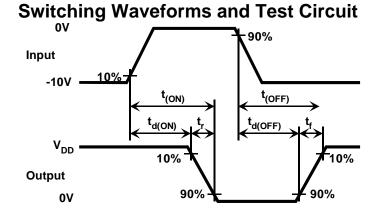
^{*} I_{D(continuous)} is limited by maximum rated T_J of 150°C

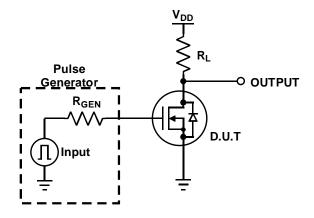
Electrical Characteristics (@25°C unless otherwise specified)

Symbol	Parameter	Min	Тур	Max	Units	Conditions	
BV _{DSX}	Drain-to-Source Breakdown Voltage				V	V_{GS} =-5 V , I_D =100 μ A	
V _{GS(OFF)}	Gate-to-Source OFF Voltage	-1.5		-3.5	V	$V_{DS}=25V$, $I_{D}=10\mu A$	
$\Delta V_{GS(OFF)}$	Change in V _{GS(OFF)} with Temperature			4.5	mV/°C	$V_{DS}=25V, I_{D}=10\mu A$	
I _{GSS}	Gate Body Leakage			100	nA	$V_{GS}=\pm20V, V_{DS}=0V$	
				1.0	μA	V _{GS} =-10V, V _{DS} =Max Rating	
I _{D(OFF)}	Drain-to-Source Leakage Current			1.0	mA	V_{GS} =-10V, V_{DS} =0.8 Max Rating, T_A =125°C	
I _{DSS}	Saturated Drain-to-source Current		500		mA	V _{GS} =0V, V _{DS} =25V	
R _{DS(ON)}	Static Drain-to-Source ON-State Resistance			42	Ω	V _{GS} =0V, I _D =100mA	
$\Delta R_{DS(ON)}$	Change in R _{DS(ON)} with Temperature			1.1	%/°C	$V_{GS}=0V$, $I_D=100mA$	
G _{FS}	Forward Transconductance	100			mmho	I _D =100mA, V _{DS} =10V	
C _{ISS}	Input Capacitance			540		\/ - 10\/ \/ -25\/	
Coss	Common Source Output Capacitance			60	pF	V_{GS} =-10V, V_{DS} =25V f=1MHz	
C_{RSS}				25			
t _{d(ON)}	Turn-ON Delay Time			30		V _{DD} =25V,	
t _r	Rise Time			45	ns	$I_{D}=25V$, $I_{D}=100$ mA, $R_{GEN}=25 \Omega$	
t _{d(OFF)}				45			
t _f	Fall Time			60		INGEN-20 32	
V_{SD}	Diode Forward Voltage Drop			1.8	V	V_{GS} =0V, I_{SD} =200mA	
t _{rr}	Reverse Recovery Time		800		ns	V_{GS} =0V, I_{SD} =200mA	

Notes:

²⁾ All AC parameters sample tested.





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^{**} Mounted on FR4, 25mm x 25mm x 1.57mm

¹⁾ All DC parameters 100% tested at 25°C unless otherwise stated. (Pulsed test: 300µs pulse at 2% duty cycle.)